

3DD4242D(T/I/M)

主要参数 MAIN CHARACTERISTICS

Ic	1.5A
V _{CEO}	400V
P _C (TO-92)	1W
P _C (TO-251\TO-252)	10W
P _C (TO-126)	20W

用途

- 节能灯
- 电子镇流器
- 高频开关电源
- 高频功率变换

APPLICATIONS

- Electronic ballasts
- High frequency switching power supply
- High frequency power transform
- 一般功率放大电路 Commonly power amplifier circuit

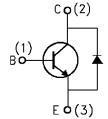
产品特性

- ●高耐压
- ●高电流容量
- ●高开关速度
- ●高可靠性
- ●环保 (RoHS) 产品 RoHS product

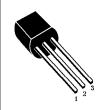
FEATURES

- High breakdown voltage
- High current capability
- High switching speed
- High reliability

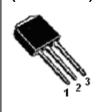
封装 Package



TO-92 (3DD4242DT)



TO-251 (3DD4242DI)



TO-126 (3DD4242DM)



TO-252 (3DD4242DUI)



订货信息 ORDER MESSAGE

订货型号	印记	无卤素	封 装	包 装
Order codes	Marking	Halogen Free	Package	Packaging
3DD4242DT-O-T-B-A	4242DT	否 NO	TO-92	编带 Brede
3DD4242DT-O-T-N-C	4242DT	否 NO	TO-92	袋装 Bag
3DD4242DI -O- I -N-B	4242DI	否 NO	TO-251	条管 Tube
3DD4242DI -O- I -N-C	4242DI	否 NO	TO-251	袋装 Bag
3DD4242DU -O- I -B-B	4242DU	否 NO	TO-252	条管 Tube
3DD4242DU -O- I -B-C	4242DU	否 NO	TO-252	袋装 Bag
3DD4242DM-O-M-N-B	4242DM	否 NO	TO-126	条管 Tube
3DD4242DM-O-M-N-C	4242DM	否 NO	TO-126	袋装 Bag





绝对最大额定值 ABSOLUTE RATINGS (Tc=25℃)

	项 目	符号	数值	单 位
Parameter			Value	Unit
集电极—发射极直流电压	Collector- Emitter Voltage (V _{BE} =0)	V _{CES}	700	V
集电极—发射极直流电压	Collector- Emitter Voltage (I _B =0)	V_{CEO}	400	V
发射极—基极直流电压	Emitter-Base Voltage	V _{EBO}	9	V
最大集电极直流电流	Collector Current (DC)	I _C	1.5	Α
最大集电极脉冲电流	Collector Current (pulse)	I _{CP}	3.0	Α
最大集电极耗散功率	Total Dissipation (TO-92)	P _C	1	W
最大集电极耗散功率	Total Dissipation (TO-251)	P _C	10	W
最大集电极耗散功率	Total Dissipation (TO-126)	P _C	20	W
最高结温	Junction Temperature	T _j	150	$^{\circ}$ C
贮存温度	Storage Temperature	T _{stg}	-55~+150	$^{\circ}\!\mathbb{C}$

电特性 ELECTRICAL CHARACTERISTIC

项 目	测试条件	最小值	典型值	最大值	单位
Parameter	Tests conditions	Value(min)	Value(typ)	Value(max)	Unit
V(BR) _{CEO}	Ic=10mA,I _B =0	400	470	-	V
V(BR) _{CBO}	Ic=1mA,I _B =0	700	800	-	V
$V(BR)_{EBO}$	I _E =1mA,Ic=0	9	16	-	V
I _{CBO}	V_{CB} =700 V , I_E =0	-	-	5	μΑ
I _{CEO}	V _{CE} =400V,I _B =0	-	-	10	μΑ
I _{EBO}	V_{EB} =7V, I_{C} =0	-	-	5	μA
hFE	V _{CE} =10V, I _C =100mA	10	20	30	-
III-E	V _{CE} =5V, I _C =1.5A	3.0	7.0	-	-
$V_{CE(sat)}$	I _C =0.5A, I _B =100mA	-	0.2	8.0	V
$V_{BE(sat)}$	I _C =0.5A, I _B =100mA	-	0.9	1.2	V
tf	V _{CC} =24V I _C =0.25A,I _{B1} =-I _{B2} =0.05A	-	-	0.7	μS
ts	V _{CC} -24 V I _C -0.23A,I _{B1} I _{B2} -0.03A	-	-	5	μS
f⊤	V _{CE} =10V, Ic=0.1A	4	-	-	MHz

热特性 THERMAL CHARACTERISTIC

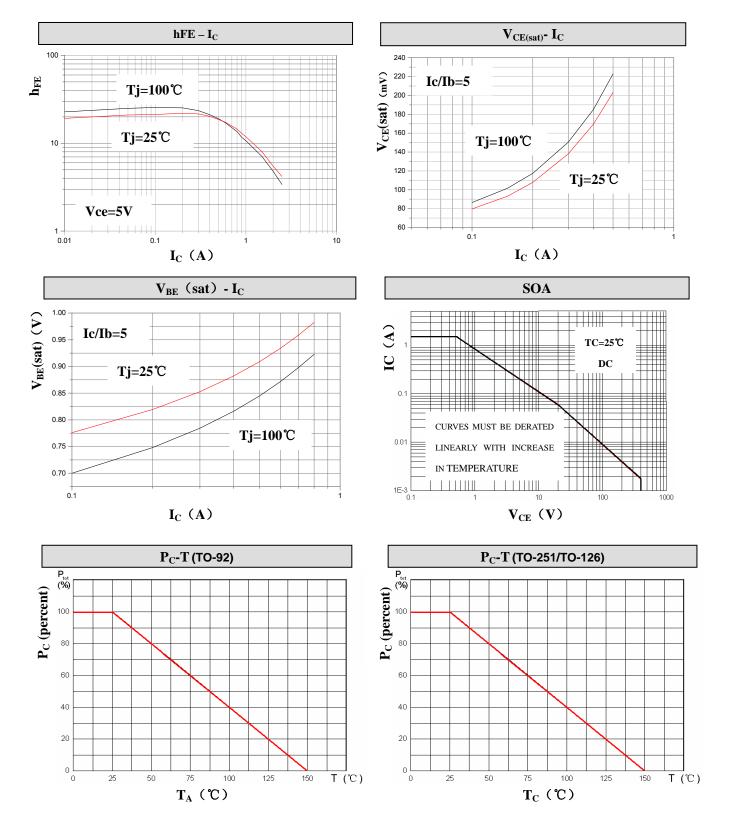
项目	符	号 最小值	最大值	单 位
Parameter	Sym	nbol Value(min)	Value(max)	Unit
结到环境的热阻 TO-92	Dunn			
Thermal Resistance Junction Case TO-92	Rth(j-a)	-	125	°C/W
结到管壳的热阻 TO-251/TO-252	Du a			
Thermal Resistance Junction Case TO-25	51/TO-252 Rth(j-c)	-	12.5	°C/W
结到管壳的热阻 TO-126	Du a			
Thermal Resistance Junction Case TO-12	26 Rth(j-c)	-	6.25	°C/W



版本: 201103B



特征曲线 ELECTRICAL CHARACTERISTICS (curves)



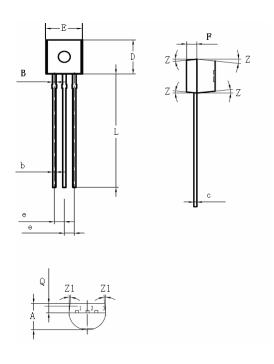




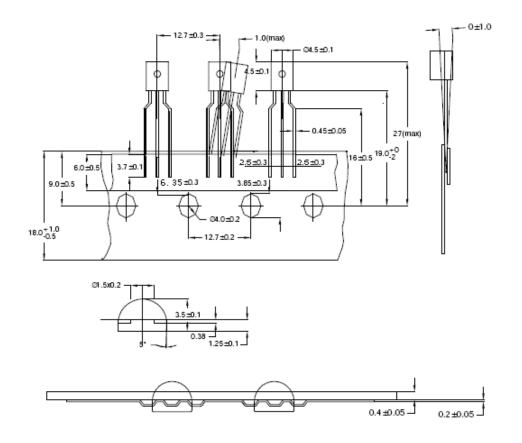
外形尺寸 PACKAGE MECHANICAL DATA

TO-92

单位 Unit: mm



Α	3.30-3.90
В	0.35-0.55
b	0.35-0.55
С	0.31-0.51
D	4.30-4.90
E	4.30-4.90
е	1.17-1.37
F	1.00-1.60
L	12.50-15.50
Q	1.00-1.60
Z	2 ⁰
Z 1	5 ⁰

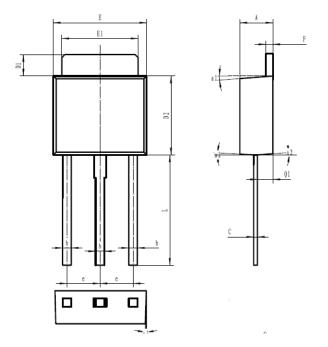






<u>外形尺</u>寸 PACKAGE MECHANICAL DATA

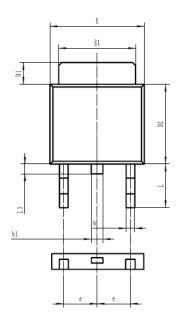
TO-251

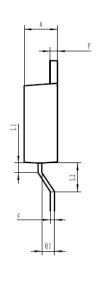


单位 Unit: mm

Α	2.20-2.40	
b	0.55-0.65	
b1	0.70-0.90	
С	0.45-0.55	
D1	1.40-1.60	
D2	5.40-5.60	
E	6.40-6.60	
E1	5.20-5.40	
е	2.25-2.35	
F	0.45-0.55	
L	7.60-7.80	
Q1	1.15-1.25	
a1	4 ° -6 °	
a2	4 ° -6 °	
а3	4 ° -6 °	

外形尺寸 PACKAGE MECHANICAL DATA TO-252





单位 Unit: mm

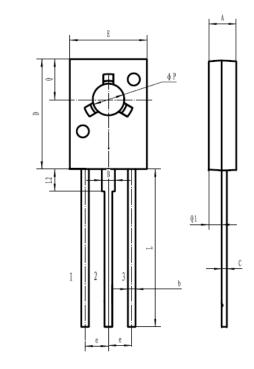
A 2.20-2.40		
=:====::0		
b 0.55-0.65		
b1 0.70-0.90		
C 0.45-0.55		
D1 1.40-1.60		
D2 5.40-5.60		
E 6.40-6.60		
E1 5.20-5.40		
e 2.25-2.35		
F 0.45-0.55		
L 2.60-2.80		
L1 0.90-1.10		
L2 1.70-1.90	1.70-1.90	
L3 0.70-0.90		
Q1 1.15-1.25	•	





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外形尺寸 PACKAGE MECHANICAL DATA



单位 Unit: mm

Α	2.50-2.90
В	1.22-1.28
С	0.30-0.70
D	10.50-11.10
E	7.10-8.10
Q	3.80-4.20
Q1	1.07-1.47
L	2.10-2.30
b	0.60-0.90
е	2.19-2.39

注意事项

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- 2.购买时请认清公司商标,如有疑问请与公司本部联系。
- 3.在电路设计时请不要超过器件的绝对最大额 定值,否则会影响整机的可靠性。
- 4.本说明书如有版本变更不另外告知

NOTE

- Jilin Sino-microelectronics co., Ltd sales its product either through direct sales or sales agent, thus, for customers, when ordering, please check with our company.
- We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.
- 3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
- 4. Jilin Sino-microelectronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.





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附录(Appendix):修订记录(Revision History)

inde (permitty) By By Charles			
日期	旧版本	新版本	修订内容
Date	Last Rev.	New Rev.	Description of Changes
2010-1-7		201001A	
2011-3-2	201001A	201103B	增加 TO-252 封装



版本: 201103B JILIN SING MIGROELECTRONICS CO., LTD 6/6